Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# 2SD1160

Switching Applications

Suitable for Motor Drive Applications

- High DC current gain
- Low saturation voltage:  $V_{CE (sat)} = 0.6 \text{ V (max) (I}_{C} = 2A, I_{B} = 40 \text{ mA})$
- Built-in free wheel diode

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	50	$(\sqrt{y})$	
Collector-emitter voltage		V <sub>CEO</sub>	20	$\bigvee$	
Emitter-base voltage		V <sub>EBO</sub>	6	У	
Collector current	DC	Ic	2	> A	
	Pulse	I <sub>CP</sub>	4	^	
Diode forward surge current (t = 1 s)		I <sub>FP</sub>	1	A	
Collector power dissipation	Ta = 25°C	PC		/w	
	Tc = 25°C	FC	10	<b>VV</b>	
Junction temperature		Tj	) 150	°C	
Storage temperature range		Tstg	-55 to 150	√ °C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

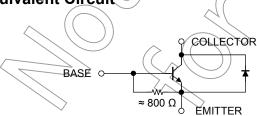
0.6MAX 0.6MAX 1 Base 2. Collector (heatsink) 3. Emitter **JEDEC** JEITA TOSHIBA 2-7B1A

Weight: 0.36 g (typ.)

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).





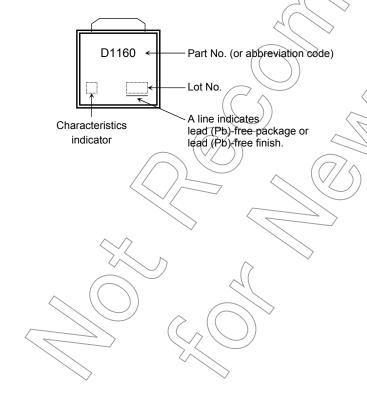
## Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0	_	_	1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	2.5	6.25	15	mA
Collector-emitter sustaining voltage	V <sub>CEO</sub> (SUS)	I <sub>C</sub> = 20 mA, L = 40 mH	20	_	_	V
DC current gain	h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1 A	100	) <del>-</del>	300	
	h <sub>FE</sub> (2)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 2 A	60	7 –	_	
Collector emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 2 A, I <sub>B</sub> = 40 mA	<b>/</b>	0.4	0.6	V
Base-emitter saturation voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 2 A, I <sub>B</sub> = 40 mA		_	1.5	V
Emitter-collector forward voltage	V <sub>ECF</sub>	I <sub>E</sub> = 1 A, I <sub>B</sub> = 0	<b>–</b>	_	2.0	V

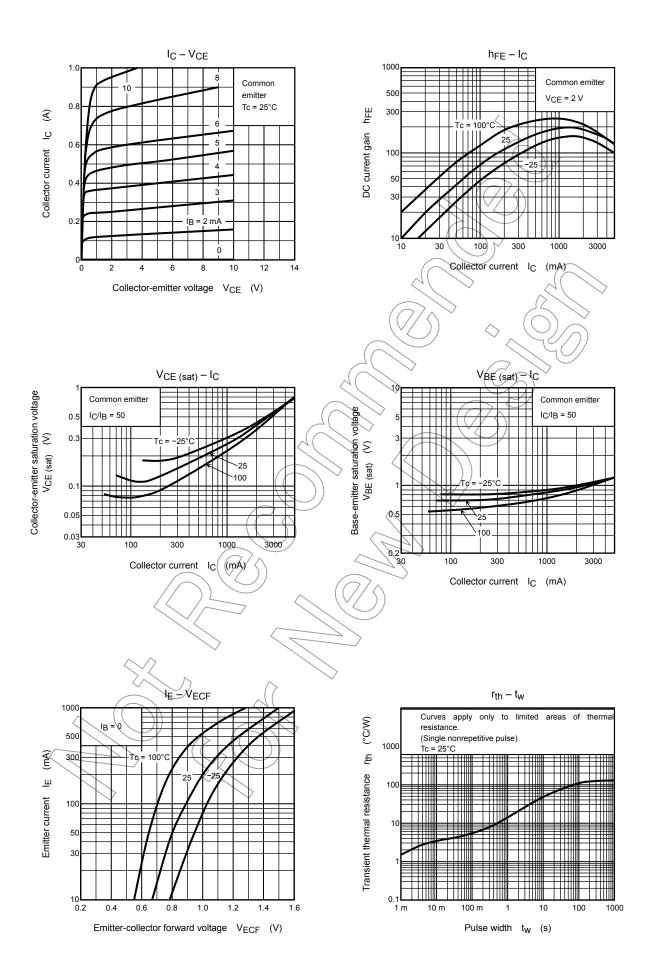
Note:	hFE (1) classification	O: 100 to 200,	Y: 150 to 300
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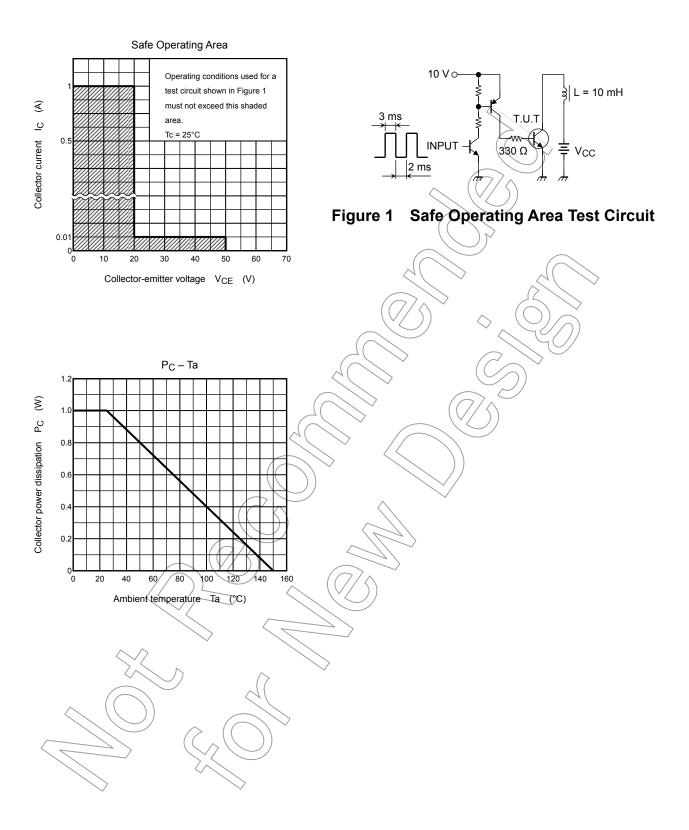
Classification	Min	Max
2SD1160-O	100	200
2SD1160-Y	150	300

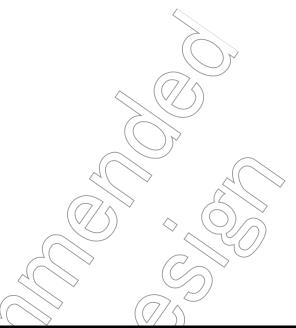
## Marking



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